

TIP35CW TIP36CW

Complementary Silicon High Power Transistors

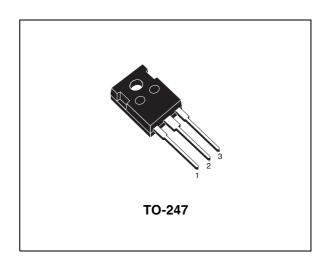
Features

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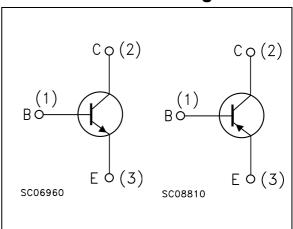
Description

The device is a silicon Epitaxial-Base NPN transistor mounted in TO-247 plastic package. It is intentend for use in power amplifier and switching applications.

The complementary PNP type is TIP36CW.



Internal Schematic Diagram



Order Codes

Part Number	Marking	Package	Packing	
TIP35CW	TIP35C W	TO-247	Tube	
TIP36CW	TIP36C W	TO-247	Tube	

1 Absolute Maximum Ratings

Table 1. Absolute Maximum Rating

Symbol	Parameter		Value	Unit
		NPN	TIP35CW	
		PNP	TIP36CW	
V _{CBO}	Collector-Base Voltage (I _E = 0)		100	V
V _{CEO}	Collector-Emitter Voltage (I _B = 0)		100	V
V _{EBO}	Emitter-Base Voltage (I _C = 0)		5	V
I _C	Collector Current		25	Α
I _{CM}	Collector Peak Current (t _p < 5ms)		50	Α
I _B	Base Current		5	Α
P _{tot}	Total Dissipation at T _c = 25°C		125	W
T _{stg}	Storage Temperature		-65 to 150	°C
TJ	Max. Operating Junction Temperature		150	°C

Note: For PNP types voltage and current values are negative.

Table 2. Thermal Data

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal Resistance Junction-Case Max	1	°C/W

TIP35CW / TIP36CW 2 Electrical Characteristics

2 Electrical Characteristics

Table 3. Electrical Characteristics ($T_{case} = 25^{\circ}C$; unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CEO}	Collector Cut-off Current (I _B = 0)	V _{CE} = 60 V			1	mA
I _{EBO}	Emitter Cut-off Current (I _C = 0)	V _{EB} = 5 V			1	mA
I _{CES}	Collector Cut-off Current (V _{BE} = 0)	V _{CE} = Rated V _{CEO}			0.7	mA
V _{CEO(sus)} Note: 1	Collector-Emitter Sustaining Voltage (I _B = 0)	I _C = 30 mA	100			V
h _{FE} Note: 1	DC Current Gain	$I_{C} = 1.5 \text{ A}$ $V_{CE} = 4 \text{ V}$ $I_{C} = 15 \text{ A}$ $V_{CE} = 4 \text{ V}$	25 10		50	
V _{CE(sat)} Note: 1	Collector-Emitter Saturation Voltage	$I_C = 15 \text{ A}$ $I_B = 1.5 \text{ A}$ $I_C = 25 \text{ A}$ $I_B = 5 \text{ A}$			1.8 4	V V
V _{BE(on)} Note: 1	Base-Emitter Voltage	$I_{C} = 15 \text{ A}$ $V_{CE} = 4 \text{ V}$ $I_{C} = 25 \text{ A}$ $V_{CE} = 4 \text{ V}$			2 4	V V
f _T	Transition Frequency	I _C = 1 A V _{CE} = 10 V f = 1 MHz	3			MHz
h _{fe}	Small Signall Current Gain	I _C = 1 A V _{CE} = 10 V f = 1 MHz	25			

Note: 1 Pulsed duration = $300 \mu s$, duty cycle $\leq 1.5\%$.

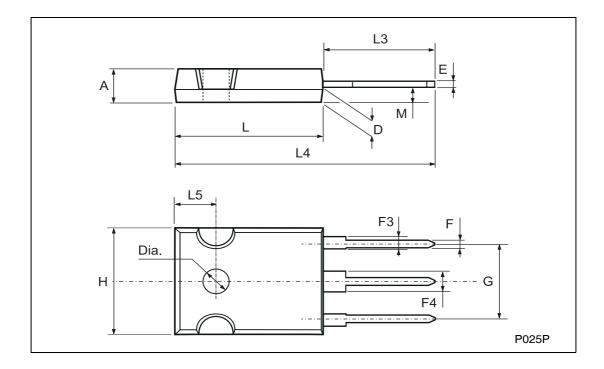
² For PNP types voltage and current values are negative.

3 Package Mechanical Data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

TO-247		\sim L	A NII4	$\sim \Lambda I$	DV.	ГΛ
10-24/	IVIC	COL	41411	CAL	. UA	

DIM.	mm			inch			
Dilvi.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Α	4.7		5.3	0.185		0.209	
D	2.2		2.6	0.087		0.102	
E	0.4		0.8	0.016		0.031	
F	1		1.4	0.039		0.055	
F3	2		2.4	0.079		0.094	
F4	3		3.4	0.118		0.134	
G		10.9			0.429		
Н	15.3		15.9	0.602		0.626	
L	19.7		20.3	0.776		0.779	
L3	14.2		14.8	0.559		0.582	
L4		34.6			1.362		
L5		5.5			0.217		
М	2		3	0.079		0.118	



4 Revision History TIP35CW / TIP36CW

4 Revision History

Date	Revision	Changes
02-Nov-2005	1	Initial release.
12-Dec-2005	2	Added the ECOPACK Label.

TIP35CW / TIP36CW 4 Revision History

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